UNIDIRECTIONAL ANISOTROPY IN MANGANITE BASED FERROMAGNETIC-ANTIFERROMAGNETIC MULTILAYERS

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1. Introduction

In mixed valence manganites a large negative magnetoresistance (MR), termed colossal magnetoresistance [1] (CMR), can be obtained due to a metal-insulator transition at the ferromagnetic Curie point [2]. However little progress has been made towards using these materials in applications, mainly due to the strong temperature dependence of the CMR effect and the large saturation fields (of the order of Tesla) required. Tunneling and grain boundary effects [3-8] as well as interface scattering [9] seem promising towards getting useful MR in these materials. In particular the high degree of spin polarization [10] makes these materials promising for spin-electronic device applications.

In view of the above considerations, recently several publications have focused on the study of trilayers and multilayers based on mixed valence manganites [11-20]. The magnetic and magnetotransport properties of such structures are not a mere superposition of the response of the individual layers. This is a result of possible interface scattering [11-17], interlayer interactions [19,20] and stress effects due to lattice mismatch between the layers [11,12,14,16].

The sensitivity of double exchange and superexchange interactions to Mn-O bond lengths and Mn-O-Mn bond angles has been used as a structural tuning mechanism of magnetic and MR properties in bulk CMR manganites [21,22]. Such changes can be engineered through various substitutions that alter the configuration of Mn-O octahedra. In epitaxial thin films, strain due to lattice mismatch can give rise to structural deformations. Thus, depending on the substrate used, the film can be under ductile or tensile strain that results in changes of magnetic anisotropy and MR properties [23-27].

In what follows we report on the magnetic structural and MR properties of La_{2/3}Ca_{1/3}MnO_{3}/La_{2/3}Ca_{1/3}MnO_{3} multilayers showing exchange biasing effects. The La_{2/3}Ca_{1/3}MnO_{3} layers are ferromagnetic (FM) and La_{2/3}Ca_{1/3}MnO_{3} layers are antiferromagnetic (AF) [28]. The structural compatibility of the AF and FM layers permits coherent growth of the superlattices that satisfy the conditions for magnetic coupling at the interfaces.

The existence of unidirectional anisotropy due to exchange coupling between a FM and an AF phase was first reported in oxide-coated fine particles of Co [29]. The exchange anisotropy results in a displaced magnetic hysteresis loop when the sample is field cooled through the Néel temperature of the AF phase. In early studies, this loop displacement has been explained by assuming an ideal FM/AF interface with uncompensated moments in the atomic-plane of the AF layer at the FM/AF boundary [29]. Up to date exchange anisotropy effects have been studied mainly in AF/FM systems consisting of transition metal alloys and metallic oxides (e.g. FM= Co, NiFe, Fe₂O₄, and AF=CoO, FeMn) [30], but not in manganites where the magnetic interactions cannot be described by direct-exchange.

2. Experimental details

The films were deposited on (001) LaAlO₃ substrates by pulsed laser deposition (PLD) from bulk stoichiometric La₂/₃Ca₁/₃MnO₃ target samples. The targets were prepared by standard solid state reaction from La₂O₃, CaCO₃ and MnO₂ powders sintered at 1300°C for 5 days with two intermediate grindings. MR measurements were performed with a four-probe method and with the current parallel to the applied magnetic field. The 0-2θ X-ray diffraction data were obtained with a Siemens D500 diffractometer using CuKα radiation and a secondary graphite monochromator. The magnetic measurements were performed in a SQUID magnetometer (Quantum Design). A series of La₂/₃Ca₁/₃MnO₃/La₁₂/₃Ca₁/₃MnO₃ multilayers with equal AF (t_AF) and (t_FM) FM layer thickness and bilayer thickness (A) ranging from 2 to 32 nm were grown along the (001) direction of the simple pseudocubic perovskite unit cell. The structural compatibility of the AF and FM layers permits coherent growth that favors magnetic coupling. In order to deposit in a multilayer form, the targets were mounted on a step-motor controlled rotatable carrier that allows the La₂/₃Ca₁/₃MnO₃ and La₁₂/₃Ca₁/₃MnO₃ targets to be sequentially exposed in the beam path. The substrate was located at a distance of 6 cm from the target, by the edge of the visible extent of the plume. The substrate temperature (Ts) was 700°C and the oxygen pressure in the chamber during the deposition was 0.03 Torr. The resulting rate at fluence of 1.5 J/cm² on the target was 0.4 Å/pulse.

3. Structural Characterization

The existence of the superstructure has been confirmed from the presence of low-angle superlattice Bragg-peaks and multiple satellite peaks around the (001), (002) and (003) Bragg-reflections of the constituents. In the low angle diffraction patterns the even order satellites are not observed due to the t_AF=t_FM=Å/2 condition.
The main Bragg peak lies between the Bragg peaks observed in single AF and FM layer films and is surrounded by satellite peaks due to the layered structure (Fig. 1). The existence of an average Bragg peak for \( \Lambda \leq 10 \) nm indicates that for this range of bilayer thickness we have a coherent layer growth. The values of \( \Lambda \) were estimated by the formula 
\[
\Lambda = \frac{n\lambda}{2} \frac{\sin \theta_n - \sin \theta_0}{\sin \theta_n + \sin \theta_0}
\]
where \( \theta_n \) are diffraction angles of the \( n \)-th order satellite and \( \theta_0 \) is the average Bragg peak. The (00\(\ell\)) LAO Bragg-peaks (\( \ell = 1,2, \) and 3) interfere with the satellite peaks adjacent to the fundamental (zeroth order) peaks of the multilayer, introducing uncertainties in the quantitative analysis of the XRD spectra. Asymmetric intensity of the satellite peaks has been reported in multilayers in which a chemical and/or strained interfacial profile is assumed along the growth direction of the superlattice. Since for all the examined \( \Lambda \) values there are no traces of mixed (001) and (110) textures, cumulative roughness effects resulting to extra surface roughness and mosaic spread with increasing \( \Lambda \) can be excluded.

4. Magnetization and Magnetoresistance Measurements

Magnetic hysteresis loops, measured at 10 K after cooling down from 300 K in zero field (ZFC) and in 10 kOe (FC), for a LaAlO$_3$/[FM(5 nm)/AF(5 nm)]$_{15}$ sample are shown in Fig. 2. It is evident that the ZFC loop is symmetric around the zero field, while the FC loop is shifted towards negative fields. This effect can be attributed to exchange biasing at the AF/FM interface, since single-layered FM films do not exhibit any loop displacement after the FC process. If \( H_1 \) is the lower and \( H_2 \) is the higher field value where the average film magnetization becomes zero, then the exchange biasing field is
defined as the loop shift \( H_{EB} = -(H_1-H_2)/2 \) and the coercivity as the halfwidth of the loop \( H_2 = (H_1-H_2)/2 \). Thus, we calculate for the FC loop an \( H_{EB}=880 \) Oe, and a \( H_C=800 \) Oe which is almost double compared to the \( H_C \) value obtained from the ZFC loop. Additional magnetic measurements were performed in order to investigate the origin of this effect. The temperature dependence of \( H_{EB} \) and \( H_c \) values is shown in Fig. 2.

![ZFC and FC loops](image)

**Figure 2.** Hysteresis loops, measured at 10 K after cooling down from 300 K in zero field (ZFC) and in 10 kOe (FC), for the \( \Lambda=10 \) nm multilayer.

Fig. 3. These values were estimated from isothermal loops measured in constant temperature intervals, after FC the sample from 300 K down to 10 K in 10 kOe and then warming up. It is evident that \( H_{EB} \) decreases and disappears around the blocking temperature \( T_B \) of 70 K. The \( H_C \) values exhibit a similar trend, indicating a connection between the mechanisms that give rise to coercivity and loop displacement. The excess coercivity observed below \( T_B \) is induced by random exchange fields at the AF/FM interfaces. This low-temperature anisotropy can be treated as an additional energy barrier in the magnetic free energy, as in the case of superparamagnetic particles [23].

Since exchange biasing is an interface related phenomenon a strong dependence on the individual FM and AF layer thickness is expected. The maximum \( H_{EB} \) is observed for the sample with \( \Lambda=10 \) nm. \( H_C \) follows the variation of \( H_{EB} \) with \( \Lambda \), indicating that there is a significant contribution in \( H_C \) from the exchange anisotropy at the AF/FM interfaces. A decrease of \( H_{EB} \) at higher \( \Lambda \) is observed as expected due to the decreased contribution of the interfaces. However \( H_{EB} \) also decreases at lower \( \Lambda \) due to the decreased contribution of the AF layers.

Additional magnetic measurements were performed in order to investigate the origin of this effect. In Fig. 4 the ZFC and FC measurements of the magnetization, normalized to the total FM volume of the sample, are shown for the above series of multilayers as a function of temperature. Both measurements were performed by warming up in 1 kOe after having cooled in zero field and 10 kOe respectively. The ZFC and FC curves coincide at temperatures higher than 100 K and become zero at about 250 K, where the Curie point \( T_C \) of the FM layers is expected. The ZFC curve exhibits a broad peak around the \( T_B \) 70 K, whereas the FC curve exhibits a steep increase just below \( T_B \). It is reasonable to assume that in the FC measurement an increase of magnetization results from the alignment of interfacial magnetic moments, giving rise to unidirectional
Figure 4. Magnetization as a function of temperature for the series of \([\text{FM}(\Lambda/2\text{nm})/\text{AF}(\Lambda/2\text{nm})]_{15}\) multilayers. The measurements were performed by warming up in 1 kOe after having cooled down to 10 K, in zero field (ZFC) and 10 kOe (FC) respectively.
Figure 5. Resistivity, normalized to the 300 K value, as a function of temperature, measured in 50 kOe ($\rho_0$) and in zero applied field ($\rho_0$) for the series of [FM($\Lambda/2$)/AF($\Lambda/2$)]$_n$ multilayers. The CMR ratio $\Delta\rho/\rho_0$ versus ($\rho_0 - \rho_L$)/$\rho_0$ is plotted as a solid line.
anisotropy [16] below $T_B$. Hence, the observed hump below $T_B$ in the ZFC curve can be attributed to thermally activated magnetic rotation over energy barriers caused by random exchange coupling at the AF/FM interfaces. Our magnetothermal measurements indicate that the $T_B$ does not change in the examined range of bilayer thickness and occurs at 70 K for all samples. To answer why $T_B$ remains more or less the same in the examined range of $\Lambda$ values it is reasonable to consider that interfacial spin ordering is confined within a few atomic planes near the AF/FM interfaces, defining an active film volume $V_{act}$. Thus, the appearance of exchange-biasing depends on the magnetic ordering of interfacial atomic planes which define a critical volume where thermal-activation energy becomes comparable to the magnetic energy at a certain blocking temperature, independent of $\Lambda$. Figure 5 shows the variation of the normalized resistivity as a function of temperature, measured in 50 kOe ($\rho_0$) and in zero applied field ($\rho_0$). The resistivity increases drastically as we cool down from 300 K, spanning almost four orders of magnitude. Also, the CMR ratio becomes maximum in the temperature range below $T_B$. In Fig.5 the steep increase of resistivity at low temperatures is in contrast to the decrease of $\rho$ observed in epitaxial FM films [24,25].

This provides further experimental evidence that the insulating behavior [26] of the AF layer is dominant at low-temperatures. This extra contribution in $\rho$ is different for every specimen and modifies the shape of the resultant CMR curves (Fig.6). Clearly, the multilayers with $\Lambda=5$ and 8 nm exhibit a peak in the CMR response, indicating a special arrangement of spins at the AF/FM interfaces. As a consequence the characteristic CMR peak, that is usually reported nearby the ferromagnetic $T_C$ of La$_2/3$Ca$_{1/3}$MnO$_3$ films [27] is not observed in the $\rho_0$ versus temperature curve. This behavior is in agreement with the magnetothermal measurements (Fig.5), where it is evident that the most drastic change of the average film magnetization does not occur near the $T_C$ of the individual FM layers but at $T_B$.

5. Conclusion

In summary, we have studied the variation of exchange biasing and coercive field as a function of $\Lambda$ and temperature in La$_{2/3}$Ca$_{1/3}$MnO$_3$/La$_{1/3}$Ca$_{2/3}$MnO$_3$ multilayers grown by PLD. The maximum $H_{EB}=880$ Oe was observed for the sample with $\Lambda=10$ nm. The exchange biasing mechanism sets-in below a blocking temperature of 70 K and induces: (i) an enhancement of $H_C$ in the FC hysteresis loops, (ii) an increase of the MR ratio due to interface scattering around $T_B$. It is interesting to note that in the series of multilayers studied here despite all variations in the AF and FM layer thicknesses $T_B$ does not vary considerably, signifying that the mechanism of spin ordering is confined within a few atomic planes near the AF/FM interfaces. This may be attributed to weak coupling of the interfacial spins to the core of the AF layer.
References

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